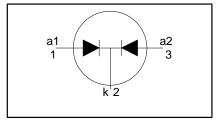
Rectifier diodes Schottky barrier

PBYR225CT series

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- low profile surface mounting package

SYMBOL



QUICK REFERENCE DATA

$$V_R = 20 \text{ V} / 25 \text{ V}$$
$$I_{O(AV)} = 2 \text{ A}$$
$$V_F \le 0.33 \text{V}$$

GENERAL DESCRIPTION

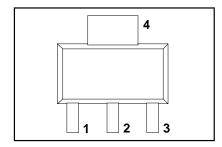
Dual, common cathode schottky rectifier diodes in a plastic envelope. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR225CT series is supplied in the surface mounting SOT223 package.

PINNING

| PIN | DESCRIPTION | |
|-----|-------------|--|
| 1 | anode 1 | |
| 2 | cathode | |
| 3 | anode 2 | |
| tab | cathode | |
| | | |

SOT223



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT |
|--------------------|---|---|------|------|---------|--------|
| | | PBYR2 | | 20CT | 25CT | |
| V_{RRM} | Peak repetitive reverse voltage | | - | 20 | 25 | V |
| V_{RWM} | Working peak reverse voltage | | - | 20 | 25 | V |
| V_R | Continuous reverse voltage | T _{sp} ≤ 97 °C | - | 20 | 25 | V |
| I _{O(AV)} | Average rectified output current (both diodes conducting) | square wave; δ = 0.5; $T_{sp} \le 136$ °C | - | 2 | 2 | Α |
| I _{FRM} | Repetitive peak forward current per diode | square wave; $\delta = 0.5$; $T_{sp} \le 136$ °C | - | 2 | 2 | Α |
| I _{FSM} | Non-repetitive peak forward current per diode | t = 10 ms t = 8.3 ms sinusoidal; $T_j = 125 ^{\circ}\text{C}$ prior to surge; with reapplied $V_{\text{RRM(max)}}$ | - | | 6 .6 | A A |
| I _{RRM} | Peak repetitive reverse surge current per diode | pulse width and repetition rate limited by T _{i max} | - | , | 1 | Α |
| T _j | Operating junction temperature per diode | j max | - | 15 | 50 | °C |
| T_{stg} | Storage temperature | | - 40 | 15 | 50 | °C |

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------|---|--|------|-----------|------|------------|
| R _{th j-sp} | Thermal resistance junction to solder point | one or both diodes conducting | | - | 15 | K/W |
| R _{th i-a} | Thermal resistance junction | pcb mounted, minimum footprint pcb mounted, pad area as in fig:1 | - | 156 70 | - | K/W K/W |

| Rectifier | diodes |
|-----------|---------|
| Schottky | barrier |

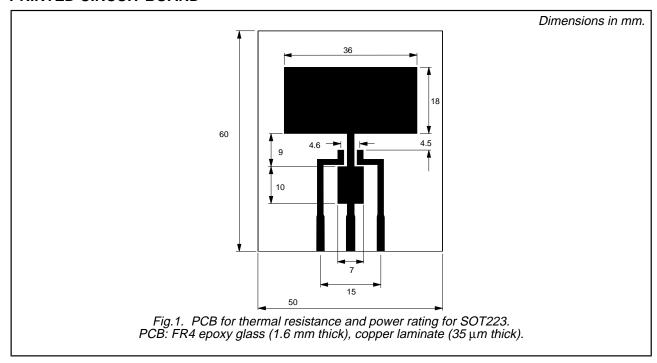
PBYR225CT series

ELECTRICAL CHARACTERISTICS

characteristics are per diode at $T_i = 25$ °C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|----------------------|--|------|------|------|------|
| V_{F} | Forward voltage | $I_F = 1 \text{ A}; T_i = 125^{\circ}\text{C}$ | - | 0.28 | 0.33 | V |
| | _ | $I_F = 2 \text{ A}$ | - | 0.42 | 0.51 | V |
| I_R | Reverse current | $\dot{V}_{R} = V_{RWM}$ | - | 0.05 | 3 | mΑ |
| | | $V_{R} = V_{RWM}$; $T_{j} = 100^{\circ}C$ | - | 5 | 10 | mΑ |
| C _d | Junction capacitance | $V_R = 5 \text{ W}$; f = 1 MHz, $T_i = 25 \text{ °C}$ to 125 °C | - | 160 | - | pF |

PRINTED CIRCUIT BOARD



Rectifier diodes Schottky barrier

PBYR225CT series

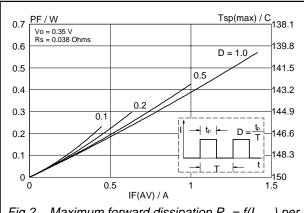


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; square current waveform where $I_{F(AV)} = I_{F(RMS)} x \sqrt{D}$.

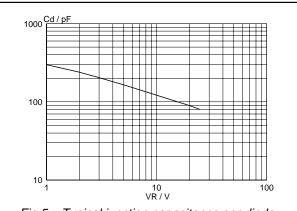


Fig.5. Typical junction capacitance per diode; $C_d = f(V_R)$; f = 1 MHz; $T_j = 25$ °C to 125 °C.

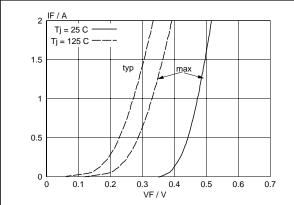


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_i

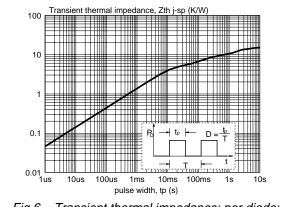


Fig.6. Transient thermal impedance; per diode; $Z_{th j-sp} = f(t_p)$.

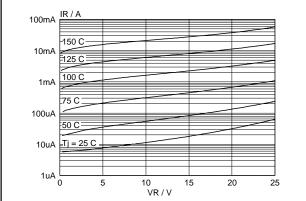
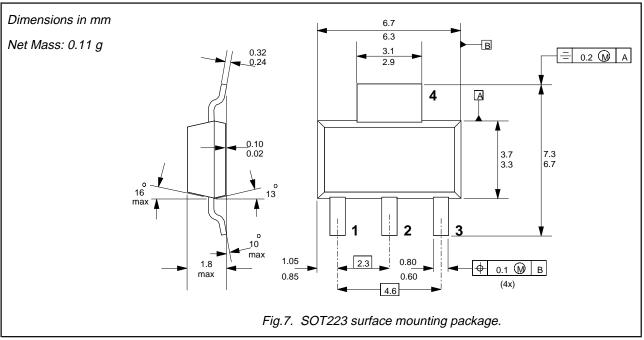


Fig.4. Typical reverse leakage current per diode; $I_R = f(V_R)$; parameter T_j

Rectifier diodes Schottky barrier

PBYR225CT series

MECHANICAL DATA



Notes

- For further information, refer to Philips publication SC18 " SMD Footprint Design and Soldering Guidelines".
 Order code: 9397 750 00505.
 Epoxy meets UL94 V0 at 1/8".

| Rectifier diodes | PBYR225CT series |
|------------------|------------------|
| Schottky barrier | |

DEFINITIONS

| Data sheet status | | | |
|---|---|--|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | | |
| Preliminary specification This data sheet contains preliminary data; supplementary data may be published late | | | |
| Product specification This data sheet contains final product specifications. | | | |
| Limiting values | | | |

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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